Samsung V-NAND SSD 980 PRO

2020 Data Sheet

Revision 1.2



LEGAL DISCLAIMER

SAMSUNG ELECTRONICS CO., LTD. RESERVES THE RIGHT TO CHANGE PRODUCTS, INFORMATION AND SPECIFICATIONS WITHOUT NOTICE.

Products and specifications discussed herein are provided for reference purposes only. All information discussed herein may change without notice and is provided on an "AS IS" basis, without warranties of any kind. This document and all information discussed herein remain the sole and exclusive property of Samsung Electronics Co., Ltd. No license of any patent, copyright, mask work, trademark or any other intellectual property right is granted under this document, by implication, estoppels or otherwise. Samsung products are not intended for use in life support, critical care, medical, safety equipment, or similar applications where product failure could result in loss of life or personal or physical harm, or any military or defense application, or any governmental procurement to which special terms or provisions may apply. For updates or additional information about Samsung products, contact your nearest Samsung representative. All brand names, trademarks and registered trademarks belong to their respective owners.

COPYRIGHT © 2020

This material is copyrighted by Samsung Electronics Co., Ltd. Any unauthorized reproductions, use or disclosure of this material, or any part thereof, is strictly prohibited and is a violation under copyright law.

TRADEMARKS & SERVICE MARKS

The Samsung logo is the trademark of Samsung Electronics Co., Ltd. All other company and product names may be trademarks of the respective companies with which they are associated.

For more information, please visit www.samsung.com/ssd and www.samsungssd.com. To download the latest software & manuals, please visit www.samsung.com/samsungssd



TECHNICAL SPECIFICATIONS

2TB GB LPDDR4			
3B LPDDR4			
3B LPDDR4			
GB LPDDR4			
Max 80.15 x Max 22.15 x Max 2.38 (mm)			
M.2 (2280)			
TBD			
5 mW TBD			
ommended)			
5% to 95% non-condensing			
20~2,000Hz, 20G			
1.5 million hours			
1,200TB			
5 years limited			
TRIM (Required OS support), Garbage Collection, S.M.A.R.T			
AES 256-bit Full Disk Encryption, TCG/Opal V2.0, Encrypted Drive (IEEE1667)			

1) 1GB = 1,000,000,000 bytes by IDEMA. A certain portion of capacity may be used for system file and maintenance use, thus the actual available capacity may differ from the labeled capacity.

980 PRO is backward compatible with PCIe 3.0. Sequential performances (up to): 3500 MB/s for reads, 2700MB/s (250GB), 3400MB/s (500GB), 3450 MB/s (1TB) for writes. Random performances (up to): 560K (250GB), 690K IOPS (500GB/1TB) for reads, 620K (250/500GB), 660K IOPS (1TB) for writes.

3) Sequential and random performance measurements are based on IOmeter1.1.0. Performance may vary based on SSD's firmware version, system hardware & configuration. Test System: AMD Ryzen 9 3900X 12-Core Processor CPU@3.79GHz, DDR4 2666MHz 16GBx2, OS-Windows 10 Pro 64bit, Chipset-ASUS-X570-ROG CROSSHAIR VIII FORMULAv

4) Sequential and random performance was measured with Intelligent TurboWrite technology being activated. The sequential read/write performances for the portion of data exceeding Intelligent TurboWrite buffer size are (up to): 4,800 MB/500 MB/s for 250GB, 6,300 MB/1,000 MB/s for 500GB, 6,800 MB /2,000 MB/s for 1TB, the random read/write performances over Intelligent TurboWrite buffer size (tested with QD 32 Thread 16) are (up to): 300K/150K IOPS for 250GB, 500K/300K IOPS for 500GB, 800K/500K IOPS for 1TB. Performance may vary depending on SSD's firmware, system hardware & configuration and other factors.

5) Power consumption is measured with IOmeter1.1.0 version with AMD Ryzen 7 3700X 8 Core @3.6GHz, DDR4 8GBx2, OS-Windows 10 Pro 64bit, Chipset-GIGABYTE-X570-AORUS MASTER

6) All documented endurance test results are in compliance with JESD218 Standards. Please visit www.jedec.org for detailed information on JESD218 Standards. TBW means Terabytes Written, Warranty provides coverage for the stated time period or the TBW, whichever comes first. Please refer to the detailed warranty statement here at <u>http://www.samsung.com/samsungssd</u>.



PRODUCT LINEUP

Density	Model Name	Box Contents	Model Code
250GB*	MZ-V8P250	Samsung SSD 980 PRO 250GB	MZ-V8P250BW
230GD	MZ-V8P250	Warranty Statement	MZ-V8P250B/AM
	MZ-V8P500	Samsung SSD 980 PRO 500GB	MZ-V8P500BW
500GB*		Warranty Statement	MZ-V8P500B/AM
1TB		Samsung SSD 980 PRO 1TB	MZ-V8P1T0BW
(1,000GB*)	MZ-V8P1T0	Warranty Statement	MZ-V8P1T0B/AM
2TB		Samsung SSD 980 PRO 2TB	MZ-V8P2T0BW
(2,000GB*)	MZ-V8P2T0	Warranty Statement	MZ-V8P2T0B/AM

* GB: 1GB = 1,000,000,000 bytes. The actual usable capacity may be less than the labeled capacity.

For more information, including but not limited to the warranty provided for this product, and to download the latest software & manuals, please visit www.samsung.com/ssd and <u>www.samsungssd.com</u>.

TEST CONFIGURATION

Below you will find a list of system configurations Samsung used to obtain the results reported in this Data Sheet. All performance data was measured with the SSD as a secondary drive

	Read/Write Performance Power Consumption		
Interface	PCIe Gen 4.0 x4	PCle Gen 4.0 x4	
OS	Windows 10 Pro 64bit	Windows 10 Pro 64bit	
CPU	AMD Ryzen 9 3900X 12-Core CPU@3.79GHz	AMD Ryzen 7 3700X 8 Core @3.6GHz	
Memory	DDR4 2666MHz 16GBx2	DDR4 8GBx2	
Chipset	ASUS-X570-ROG CROSSHAIR VIII FORMULAv	GIGABYTE-X570-AORUS MASTER	
Test Program	IOmeter 1.1.0	IOmeter 1.1.0	

The test values in the review were obtained under the following BIOS settings.

1) BIOS version: 1201(2019/11/18)

- 2) Advanced/AMD CBS/CPU Common Options/Global C-state Control: Auto -> Disabled
- 3) Overclock
 - 3-1) Ai Overclock Tuner: Default -> Manual
 - 3-2) Memory Frequency: Auto -> DDR4-3600MHz
 - 3-3) Core Performance Boost: Auto -> Disabled
 - 3-4) CPU Core Ratio: Auto -> 43.75
 - 3-5) Precision Boos Overdrive/Precision Boost Overdrive: Auto -> Disabled
 - 3-6) DRAM Timing Control/DRAM CAS# Latency: Auto -> 17
 - DRAM Timing Control/Trcdrd : Auto -> 19
 - DRAM Timing Control/Trcdwr : Auto -> 19
 - DRAM Timing Control/DRAM RAS# PRE Time: Auto -> 18
 - DRAM Timing Control/DRAM RAS# ACT Time: Auto -> 36
 - 3-7) DRAM Voltage: Auto -> 1.35

SAMSUNG

Revision History

Revision Number	Description	Revision Date
1.0	Initial Release	August, 2020
1.1	SKU information and test configuration is added	September, 2020
1.2	After TurboWrite performance for read is updated	September, 2020